

FCC week 2018

Study on Cryogenic Properties of SC Thin Films on Substrate

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April 12, 2018

Amsterdam



EASITrain – European Advanced Superconductivity Innovation and Training. This Marie Skłodowska-Curie Action (MSCA) Innovative Training Networks (ITN) has received funding from the European Union's H2020 Framework Programme under Grant Agreement no. 764879

The people

CERN				Uni Siegen	HZB	INFN-LNL
TE-CRG-CI	BE-RF-SRF	TE-VSC-SCC	TE-VSC-VSM			
Cryolab						
Torsten Koettig	Hernan F. Furci	Guillaume J. Rosaz	Sergio Calatroni	Prof. Jens Knobloch		
Johan Bremer				Stewart Leith (ESR14)		Vanessa Garcia Diaz (ESR10)

ESR1 main objectives

Experimentally qualify methods used by CERN for deposited layers and their quality

- Characterization of thermal properties of superconducting (SC) thin films deposited on substrate at low temperatures
- Development of a model and perform numerical simulation to predict the influence of thermal properties on the SC performance
- Compare results with ESR10 (INFN-LNL) and ESR14 (UniSiegen)

PhD objectives

On top of/parallel to ESR1 project:

- Characterizing the thermal parameters of the cooling path from the thin film towards the cold source (saturated He bath at/below 4.2 K), with special attention to the transition of He I to He II
- Interface thermal resistance
V Palmieri and R Vaglio 2016 Supercond. Sci. Technol. 29 015004
- Extend the study to cavity structures with RF fields
- Participate in the SC cavity quench localization study

Plan and tasks – Year 1

- Literature research and gain of knowledge
- Definition of needs for the setup of the experimental test stations
 - Samples [CERN TE/VSC and BE/RF groups]
 - Measurement precision [CERN TE/VSC and BE/RF groups]
 - Data analysis [CERN TE/VSC and BE/RF groups, INFN-LNL, UniSiegen]
- Upgrade of existing test facilities and investigation of the possibility to establish a cryocooler setup to access variable temperatures in vacuum environment for RRR measurements

Test stands at Cryolab

Thermal expansion
4.2 K and 78 K



Set-up in LHe/LN₂
Bulk material samples

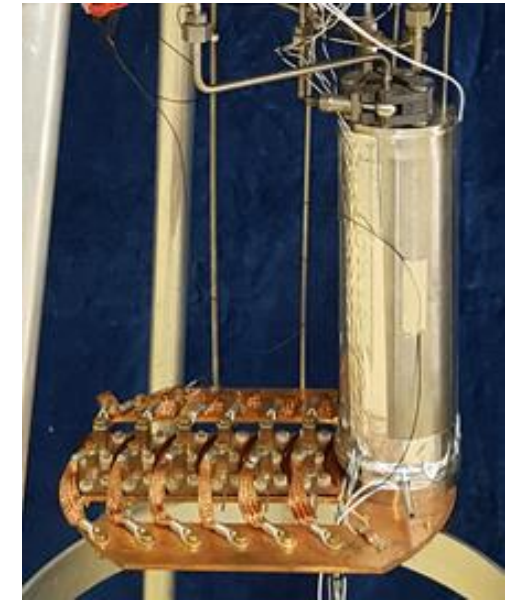
RRR and T_c of SC on substrates or bulk SC
4.2 K to 300 K



Set-up in He vapor
Nb on sapphire
Nb on quartz



Set-up in He vapor
SC on foil

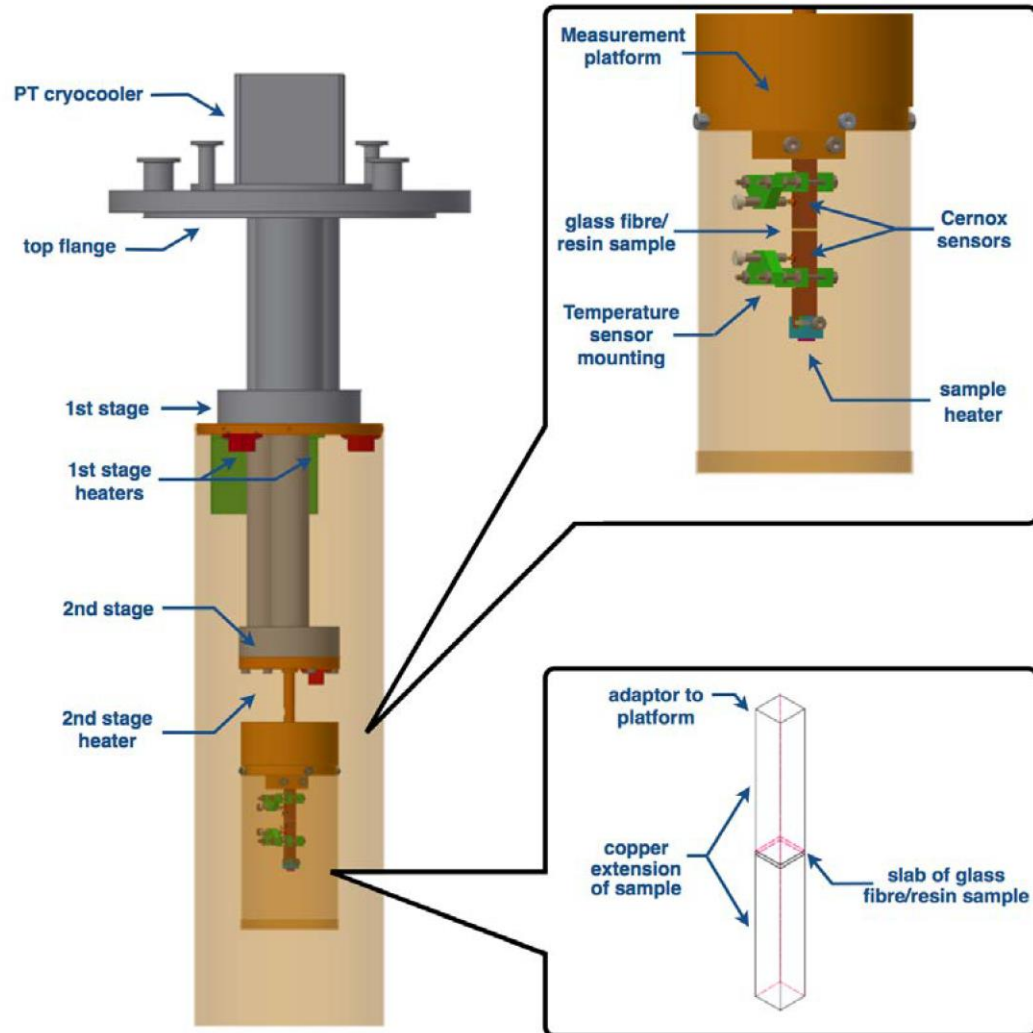


Set-up in vacuum
Bulk material samples
Curved and straight shape

Plan and tasks – Year 2

- Prepare a test stand to determine T_c of the thin films on metallic (Cu) substrate by magnetic induction in LHe environment (S. Calatroni, G. Rosaz from CERN TE/VSC)
- Study the interface thermal resistance of the SC film to its substrate (understand the feasibility of a Cryocooler-based thermal conductivity test stand)
- Develop a numerical simulation tool to study the transient thermal behavior of SC thin film structures (e.g. SC cavity geometries) [CERN BE/RF-SRF]

Thermal conductivity test stand



Existing test stand to measure thermal conductivity between 3 K and 290 K

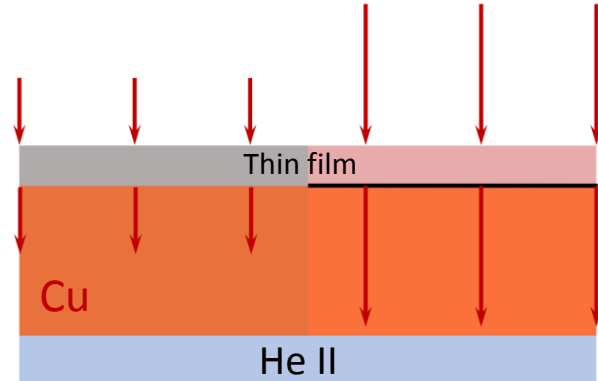
- Pulse Tube Cryocooler (PTC) based cold platform
→ sample in vacuum environment
- first stage of the PTC at 45 K: thermal shield and heat intercept
- second stage of the PTC: $T = 2.6 \text{ K}$ to 20 K
- experimental platform: $T = 3 \text{ K}$ to 30 K (100 K extended, during warm up to 290 K) and second shield thermalized at sample temperature

Plan and tasks – Year 3

- Characterization of SC films as cavity structures with RF field
[Marco Arzeo's talk "Quadrupole resonators characterisation"](#)
[FCC week 2018 – yesterday April 10th](#)
- Comparison of the RF performance of SC thin films on substrate, in vacuum and He-bath cooling environment
- Participation in/contribution to the Quench Localization Study by using synergy effects between the Cryolab and the Cavity Diagnostics Project [CERN BE/RF-SRF]
- Writing of PhD thesis

Quench Localization Study

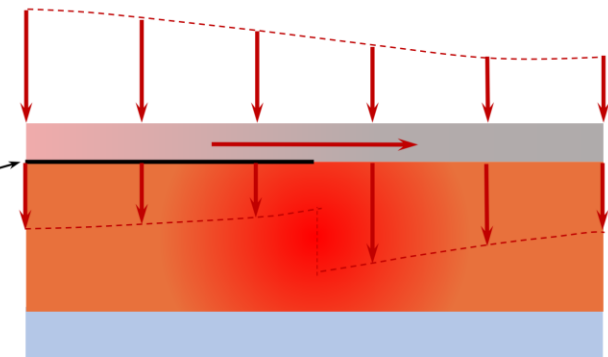
Only perpendicular conduction



$$Q_{RF} = \frac{1}{2} R_s(T_f, \omega, B) \left(\frac{B}{\mu_0} \right)^2$$

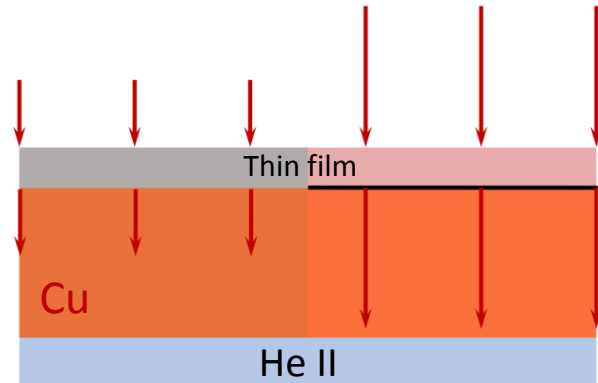
Localized thermal barrier

With lateral conduction



Quench Localization Study

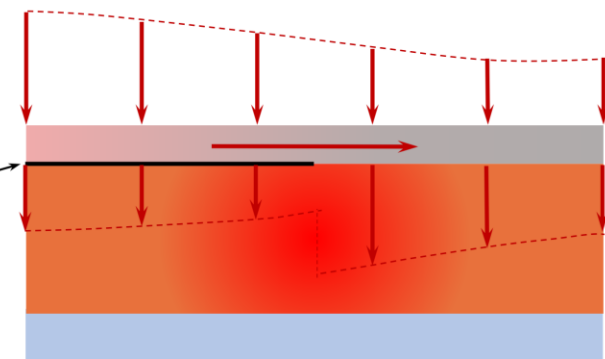
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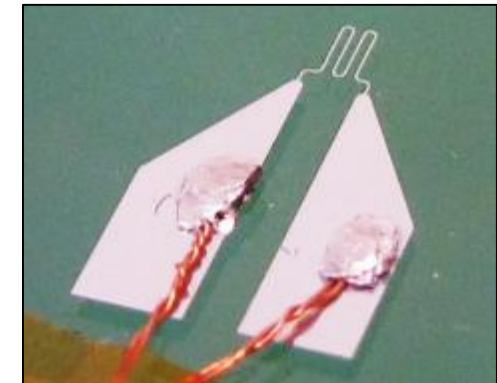


Oscillating Superleak Transducer



- sensitivity for 2nd sound in He II
- spatial resolution for quench localisation
- gaining further information from the temperature wave propagating in 3D

Transition Edge Sensor



Risks and challenges

- Nb_3Sn brittle
- Production of samples
- Characterization of SC film on Cu substrate is new
- Coordination with groups providing samples and know-how
- ...

Thank you. Questions?

